NSN 5961-00-412-0907

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-412-0907 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Overall Diameter:** 2.500 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 400.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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